

Technical documentation



Support & training



SN54HCT244, SN74HCT244 SCLS175G – MARCH 2003 – REVISED DECEMBER 2022

SNx4HCT244 Octal Buffers and Line Drivers With 3-State Outputs

1 Features

- Operating Voltage Range of 4.5 V to 5.5 V
- High-Current Outputs Drive up to 15 LSTTL Loads
- Low Power Consumption: 80-µA Maximum I_{CC}
- Typical t_{pd} = 13 ns
- ±6-mA Output Drive at 5 V
- Low Input Current of 1 µA Maximum
- Inputs Are TTL-Voltage Compatible
- 3-State Outputs Drive Bus Lines and Buffer Memory Address Registers

2 Applications

- Servers
- LED Displays
- Network Switches
- Telecom Infrastructure
- Motor Drivers
- I/O Expanders

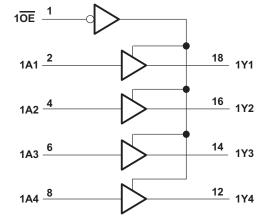
3 Description

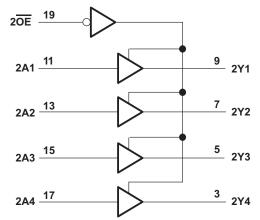
These octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clockdrivers, and bus-oriented receivers and transmitters. The SNx4HCT244 devices are organized as two 4-bit buffers or drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes noninverted data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

Device Information

| PART NUMBER | PACKAGE ⁽¹⁾ | BODY SIZE (NOM) | | | | | | | | |
|--------------|------------------------|--------------------|--|--|--|--|--|--|--|--|
| | DB (SSOP, 20) | 7.20 mm × 5.30 mm | | | | | | | | |
| | DW (SOIC, 20) | 12.80 mm × 7.50 mm | | | | | | | | |
| SN74HCT244 | N (PDIP, 20) | 24.33 mm × 6.35 mm | | | | | | | | |
| | NS (SO, 20) | 12.60 mm × 5.30 mm | | | | | | | | |
| | PW (TSSOP, 20) | 6.50 mm × 4.40 mm | | | | | | | | |
| | DGS (VSSOP, 20) | 5.10 mm × 3.00 mm | | | | | | | | |
| SN54HCT244 | J (CDIP, 20) | 24.20 mm × 6.92 mm | | | | | | | | |
| 310341101244 | FK (LCCC, 20) | 8.89 mm × 8.89 mm | | | | | | | | |

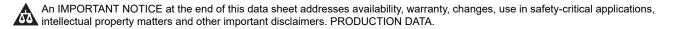
(1) For all available packages, see the orderable addendum at the end of the data sheet.





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Logic Diagram (Positive Logic)





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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

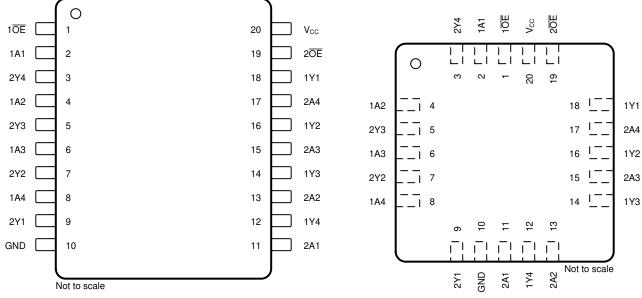
| С | hanges from Revision F (May 2022) to Revision G (December 2022) | Page |
|---|---|------|
| • | Added DGS (SOT) package information | 1 |
| | Added DGS (SOT) package information | |
| | Added DGS (SOT) package thermal information | |
| | | |

Changes from Revision E (August 2016) to Revision F (May 2022)

| С | hanges from Revision D (August 2013) to Revision E (August 2016) | Page |
|---|--|----------------|
| • | Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and | |
| | Documentation Support section, and Mechanical, Packaging, and Orderable Information section Deleted Ordering Information table; see POA at the end of the data sheet | <mark>1</mark> |
| | Changed <i>Thermal Information</i> table Added ESD warning | |



5 Pin Configuration and Functions



J, W, DB, DW, N, NS, PW or DGS Packages 20-Pin CDIP, CFP, SSOP, SOIC, PDIP, SO, TSSOP or VSSOP Top View

FK Package 20-Pin LCCC Top View

| | Pin Functions | | | | | | | | |
|-----|-----------------|--------------------|---------------|--|--|--|--|--|--|
| | PIN | I/O ⁽¹⁾ | DESCRIPTION | | | | | | |
| NO. | NAME | | DESCRIPTION | | | | | | |
| 1 | 1 OE | I | Output enable | | | | | | |
| 2 | 1A1 | I | Input | | | | | | |
| 3 | 2Y4 | 0 | Output | | | | | | |
| 4 | 1A2 | I | Input | | | | | | |
| 5 | 2Y3 | 0 | Output | | | | | | |
| 6 | 1A3 | I | Input | | | | | | |
| 7 | 2Y2 | 0 | Output | | | | | | |
| 8 | 1A4 | I | Input | | | | | | |
| 9 | 2Y1 | 0 | Output | | | | | | |
| 10 | GND | _ | Ground | | | | | | |
| 11 | 2A1 | I | Input | | | | | | |
| 12 | 1Y4 | 0 | Output | | | | | | |
| 13 | 2A2 | I | Input | | | | | | |
| 14 | 1Y3 | 0 | Output | | | | | | |
| 15 | 2A3 | I | Input | | | | | | |
| 16 | 1Y2 | 0 | Output | | | | | | |
| 17 | 2A4 | I | Input | | | | | | |
| 18 | 1Y1 | 0 | Output | | | | | | |
| 19 | 2 OE | I | Output enable | | | | | | |
| 20 | V _{CC} | _ | Power pin | | | | | | |

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | | MIN | MAX | UNIT |
|------------------|---|--|------|-----|------|
| V _{CC} | Supply voltage | | -0.5 | 7 | V |
| I _{IK} | Input clamp current ⁽²⁾ | $V_{I} < 0 \text{ or } V_{I} > V_{CC}$ | | ±20 | mA |
| I _{OK} | Output clamp current ⁽²⁾ | V_{O} < 0 or V_{O} > V_{CC} | | ±20 | mA |
| lo | Continuous output current | $V_{O} = 0$ to V_{CC} | | ±35 | mA |
| | Continuous channel current through V_{CC} or GND | | | ±70 | mA |
| TJ | Junction temperature | | | 150 | °C |
| T _{stg} | Storage temperature | | -65 | 150 | °C |

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 ESD Ratings

| | | | VALUE | UNIT | | | | |
|--|---|--|-------|------|--|--|--|--|
| SN74HCT244 in DB, DW, N, NS, or PW package | | | | | | | | |
| V | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | V | | | | |
| V _(ESD) | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | ±1000 | v | | | | |
| SN54HC | SN54HCT244 in J, W, or FK package | | | | | | | |
| V _(ESD) | V _(ESD) Electrostatic discharge Human-body model (HBM) | | ±1500 | V | | | | |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | | MIN | NOM | MAX | UNIT |
|-----------------|-------------------------------------|----------------------------------|-----|-----|----------|------|
| V _{CC} | Supply voltage | | 4.5 | 5 | 5.5 | V |
| V _{IH} | High-level input voltage | V _{CC} = 4.5 V to 5.5 V | 2 | | | V |
| V _{IL} | Low-level input voltage | V _{CC} = 4.5 V to 5.5 V | | | 0.8 | V |
| VI | Input voltage | | 0 | | V_{CC} | V |
| Vo | Output voltage | | 0 | | V_{CC} | V |
| Δt/Δv | Input transition rise and fall time | | | | 500 | ns |
| т. | Operating free-air temperature | SN54HCT244 | -55 | | 125 | °C |
| IA | | SN74HCT244 | -40 | | 85 | C |

All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the *Implications of Slow or Floating CMOS Inputs* application report.



6.4 Thermal Information

| | | | SN74HCT244 | | | | | |
|------------------------|---|-----------|------------|----------|---------|---------------|----------------|------|
| | | DW (SOIC) | DB (SSOP) | N (PDIP) | NS (SO) | PW (TSSOP) | DGS (VSSOP) | |
| THERMAL | | 20 PINS | 20 PINS | 20 PINS | 20 PINS | 20 PINS | 20 PINS | UNIT |
| R _{θJA} | Junction-to-ambient thermal resistance ⁽¹⁾ | 109.1 | 122.7 | 84.6 | 113.4 | 131.8 | 130.6 | °C/W |
| R _{θJC (top)} | Junction-to-case (top) thermal resistance | 76 | 81.6 | 72.5 | 78.6 | 72.2 | 68.7 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 77.6 | 77.5 | 65.3 | 78.4 | 82.8 | 85.4 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 51.5 | 46.1 | 55.3 | 47.1 | 21.5 | 10.5 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 77.1 | 77.1 | 65.2 | 78.1 | 82.4 | 85.0 | °C/W |
| R _{θJC (bot)} | Junction-to-case (bottom) thermal resistance | N/A | N/A | N/A | N/A | N/A | N/A | °C/W |

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIO | NS | Vcc | MIN | TYP | MAX | UNIT |
|---------------------------------|--|--------------------------|-----------------------|-------|------|-------|-------|------|
| | | | T _A = 25°C | | 4.4 | 4.499 | | |
| | | I _{OH} = –20 μA | SN54HCT244 | | 4.4 | | | V |
| N/ | | | SN74HCT244 | 4.5 V | 4.4 | | | |
| V _{OH} | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | T _A = 25°C | 4.5 V | 3.98 | 4.3 | | v |
| | | I _{OH} = –6 mA | SN54HCT244 | | 3.7 | | | |
| | | | SN74HCT244 | | 3.84 | | | |
| | | | T _A = 25°C | | | 0.001 | 0.1 | |
| V _{OL} | | I _{OL} = 20 μA | SN54HCT244 | | | | 0.1 | |
| | VI = VIH or VII | | SN74HCT244 | 4.5 V | | | 0.1 | V |
| VOL | | | T _A = 25°C | 4.5 V | | 0.17 | 0.26 | |
| | | I _{OL} = 6 mA | SN54HCT244 | | | | 0.4 | |
| | | | SN74HCT244 | | | | 0.33 | |
| | V _I = V _{CC} or 0 | T _A = 25°C | _= 25°C | | | ±0.1 | ±100 | nA |
| I _I | | SN54HCT244 | | 5.5 V | | | ±1000 | |
| | | SN74HCT244 | | | | | ±1000 | |
| | $V_{O} = V_{CC} \text{ or } 0,$ | T _A = 25°C | | | | ±0.01 | ±0.5 | |
| I _{OZ} | $V_{O} = V_{CC} \text{ or } 0, \qquad T_{A} = 25^{\circ}C$ $V_{I} = V_{IH} \text{ or } V_{IL} \qquad SN54HCT244$ | | | 5.5 V | | | ±10 | μA |
| | | SN74HCT244 | | | | | ±5 | |
| | | T _A = 25°C | | | | | 8 | |
| I _{CC} | $V_{I} = V_{CC} \text{ or } 0,$ $I_{O} = 0$ | SN54HCT244 SN74HCT244 | | 5.5 V | | | 160 | μA |
| | | | | | | | 80 | |
| | One input at 0.5 V | T _A = 25°C | | | | 1.4 | 2.4 | |
| ΔI _{CC} ⁽¹⁾ | or 2.4 V, Other inputs at 0 or | SN54HCT244 | | 5.5 V | | | 3 | mA |
| | V _{CC} | SN74HCT244 | | | | | 2.9 | |



over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | V _{cc} | MIN | TYP | MAX | UNIT |
|----------------|-----------------------|-------------------|-----|-----|-----|------|
| | T _A = 25°C | | | 3 | 10 | |
| C _i | SN54HCT244 | 4.5 V to 5.5 V | | | 10 | pF |
| | SN74HCT244 | | | | 10 | |

(1) This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V_{CC}.

6.6 Switching Characteristics: C_L = 50 pF

over recommended operating free-air temperature range, CL = 50 pF (unless otherwise noted) (see Figure 7-1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | v_{cc} | TEST CONDITIONS | MIN | ТҮР | МАХ | UNIT | |
|-----------|-----------------|----------------|----------|-----------------------|-----|-----|-----|------------|--|
| | | | | T _A = 25°C | | 15 | 28 | | |
| | | | 4.5 V | SN54HCT244 | | | 42 | | |
| | А | Y | | SN74HCT244 | | | 35 | n 0 | |
| pd | A | ř | | T _A = 25°C | | 13 | 25 | ns | |
| | | | 5.5 V | SN54HCT244 | | | 38 | | |
| | | | | SN74HCT244 | | | 32 | | |
| | | | | T _A = 25°C | | 21 | 35 | | |
| | | | 4.5 V | SN54HCT244 | | | 53 | | |
| | ŌĒ | Y | | SN74HCT244 | | | 44 | | |
| ten | | Ŷ | | T _A = 25°C | | 19 | 32 | ns | |
| | | | 5.5 V | SN54HCT244 | | | 48 | ns | |
| | | | | SN74HCT244 | | | 40 | | |
| | | | | T _A = 25°C | | 19 | 35 | | |
| | | | 4.5 V | SN54HCT244 | | | 53 | | |
| | ŌĒ | Y | | SN74HCT244 | | | 44 | | |
| dis | UE | Ŷ | | T _A = 25°C | | 18 | 32 | | |
| | | | 5.5 V | SN54HCT244 | | | 48 | | |
| | | | | SN74HCT244 | | | 40 | | |
| | | | | T _A = 25°C | | 8 | 12 | | |
| | | | 4.5 V | SN54HCT244 | | | 18 | | |
| | | X | | SN74HCT244 | | | 15 | | |
| ł | | Y | | T _A = 25°C | | 7 | 11 | ns | |
| | | | 5.5 V | SN54HCT244 | | | 16 | | |
| | | | | SN74HCT244 | | | 14 | | |

6.7 Switching Characteristics: C_L = 150 pF

over recommended operating free-air temperature range, $C_L = 150 \text{ pF}$ (unless otherwise noted) (see Figure 7-1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{cc} | TEST CONDITIONS | MIN | ТҮР | МАХ | UNIT |
|-----------|-----------------|----------------|-----------------|-----------------------|-----|-----|-----|------|
| | | | | T _A = 25°C | | 21 | 45 | |
| | | Y | 4.5 V | SN54HCT244 | | | 68 | |
| | | | | SN74HCT244 | | | 56 | |
| lpd | A | | | T _A = 25°C | | 18 | 40 | ns |
| | | | 5.5 V | SN54HCT244 | | | 61 | |
| | | | | SN74HCT244 | | | 51 | |



over recommended operating free-air temperature range, $C_L = 150 \text{ pF}$ (unless otherwise noted) (see Figure 7-1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{cc} | TEST CONDITIONS | MIN | ТҮР | MAX | UNIT |
|--------------------|-----------------|----------------|-----------------------|-----------------------|-----|-----|-----|------|
| t _{en} OE | | | | T _A = 25°C | | 25 | 52 | |
| | | | 4.5 V | SN54HCT244 | | | 79 | |
| | Y | | SN74HCT244 | | | 65 | | |
| | ř | | T _A = 25°C | | 22 | 47 | ns | |
| | | | 5.5 V | SN54HCT244 | | | 71 | |
| | | | | SN74HCT244 | | | 59 | |
| | | | | T _A = 25°C | | 17 | 42 | |
| | | | 4.5 V | SN54HCT244 | | | 63 | |
| • | | Y | | SN74HCT244 | | | 53 | |
| t _t | | ř | | T _A = 25°C | | 14 | 38 | ns |
| | | | 5.5 V | SN54HCT244 | | | 57 | |
| | | | | SN74HCT244 | | | 48 | |

6.8 Operating Characteristics

T_A = 25°C

| | PARAMETER | TEST CONDITIONS | TYP | UNIT |
|-----------------|--|-----------------|-----|------|
| C _{pd} | Power dissipation capacitance per buffer or driver | No load | 40 | pF |

6.9 Typical Characteristics

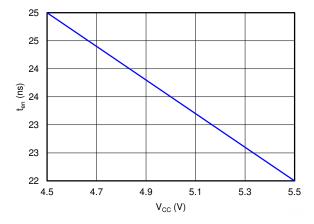
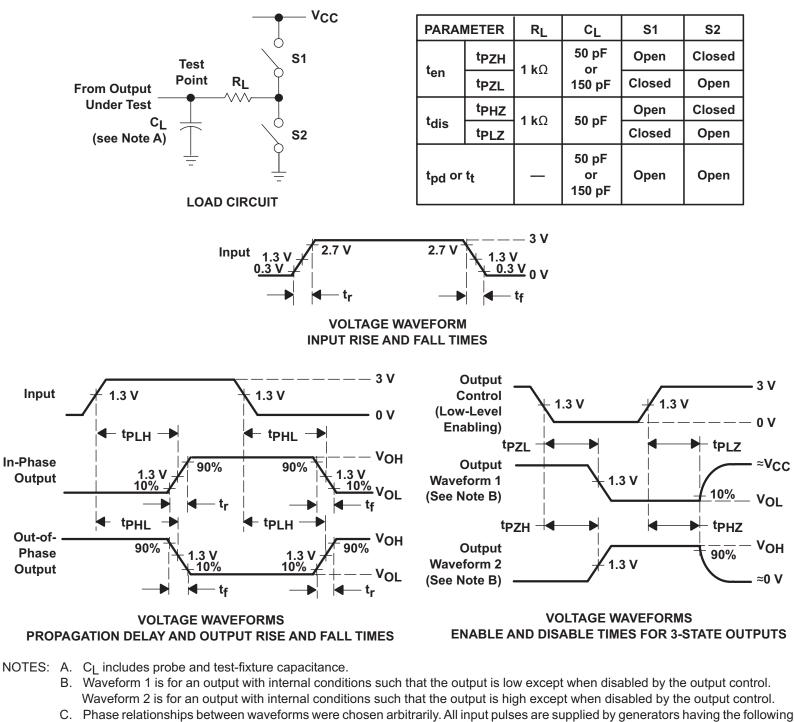


Figure 6-1. Enable Time vs V_{CC}





- characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r = 6 ns, t_f = 6 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. tpLH and tpHL are the same as tpd.

Figure 7-1. Load Circuit and Voltage Waveforms

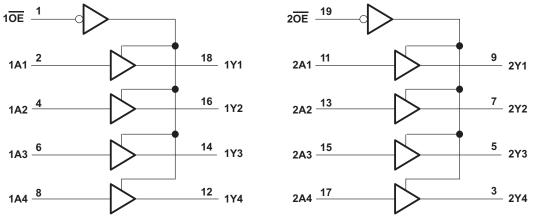


8 Detailed Description

8.1 Overview

The SNx4HCT244 device is organized as two 4-bit buffers and line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state. To ensure the high-impedance state during power up or power down, \overline{OE} must be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

8.2 Functional Block Diagram



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Figure 8-1. Logic Diagram (Positive Logic)

8.3 Feature Description

The SN74HCT244 device can drive up to 15 LSTTL loads. This device has low power consumption of 80- μ A I_{CC}. The SN74HCT244 also has 3 state outputs that allow the outputs to go to high impedance, low or high.

8.4 Device Functional Modes

Table 8-1 lists the functions of the SNx4HC244.

| lable | Table 8-1. Function Table | | | | | | | | |
|-------|---------------------------|--------|--|--|--|--|--|--|--|
| INP | UTS | OUTPUT | | | | | | | |
| ŌĒ | Α | Y | | | | | | | |
| L | Н | Н | | | | | | | |
| L | L | L | | | | | | | |
| Н | Х | Z | | | | | | | |



9 Application and Implementation

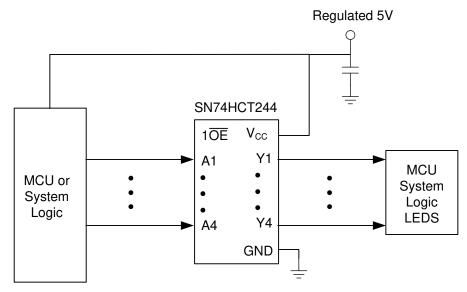
Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The SN74HC244 is a high-drive CMOS device that can be used for a multitude of bus interface type applications where output drive or PCB trace length is a concern.

9.2 Typical Application



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Figure 9-1. Application Schematic

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Avoid bus contention because it can drive currents in excess of maximum limits. The high drive creates fast edges into light loads, so consider routing and load conditions to prevent ringing.

9.2.2 Detailed Design Procedure

- 1. Recommended input conditions:
 - For rise time and fall time specifications, see $\Delta t/\Delta V$ in *Recommended Operating Conditions*.
 - For specified high and low levels, see V_{IH} and V_{IL} in *Recommended Operating Conditions*.
- 2. Recommend output conditions:
 - Load currents must not exceed the I_O maximum per output and must not exceed the continuous current through V_{CC} or GND total current for the part. These limits are located in *Absolute Maximum Ratings*.
 - Outputs must not be pulled above V_{CC}.



9.2.3 Application Curve

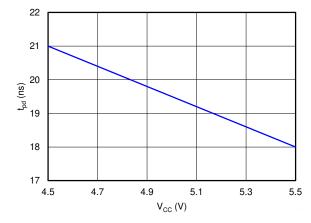


Figure 9-2. Propagation Delay vs V_{CC}

10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in *Recommended Operating Conditions*.

Each V_{CC} terminal must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends a 0.1- μ F capacitor. If there are multiple V_{CC} terminals, then TI recommends 0.01- μ F or 0.022- μ F capacitors for each power terminal. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. Multiple bypass capacitors may be paralleled to reject different frequencies of noise. The bypass capacitor must be installed as close to the power terminal as possible for the best results.

11 Layout

11.1 Layout Guidelines

When using multiple bit logic devices, inputs must not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input and gate are used, or when only 3 of the 4-buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 11-1 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally they are tied to GND or V_{CC} , whichever makes more sense or is more convenient.

11.2 Layout Example



Figure 11-1. Layout Diagram



12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation, see the following:

Implications of Slow or Floating CMOS Inputs (SCBA004)

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

| | Table 12-1. Related Links | | | | | | | | | | | |
|------------|---------------------------|--------------|------------------------|---------------------|------------------------|--|--|--|--|--|--|--|
| PARTS | PRODUCT FOLDER | SAMPLE & BUY | TECHNICAL DOCUMENTS | TOOLS & SOFTWARE | SUPPORT & COMMUNITY | | | | | | | |
| SN54HCT244 | Click here | Click here | Click here | Click here | Click here | | | | | | | |
| SN74HCT244 | Click here | Click here | Click here | Click here | Click here | | | | | | | |

Table 12-1. Related Links

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.5 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|---------------------|--------------------------------------|----------------------|--------------|-------------------------------------|---------|
| 5962-8513001VRA | ACTIVE | CDIP | J | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 5962-8513001VR A SNV54HCT244J | Samples |
| 5962-8513001VSA | ACTIVE | CFP | W | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 5962-8513001VS A SNV54HCT244W | Samples |
| 85130012A | ACTIVE | LCCC | FK | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 85130012A SNJ54HCT 244FK | Samples |
| 8513001RA | ACTIVE | CDIP | J | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 8513001RA SNJ54HCT244J | Samples |
| JM38510/65755B2A | ACTIVE | LCCC | FK | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | JM38510/ 65755B2A | Samples |
| JM38510/65755BRA | ACTIVE | CDIP | J | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | JM38510/ 65755BRA | Samples |
| M38510/65755B2A | ACTIVE | LCCC | FK | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | JM38510/ 65755B2A | Samples |
| M38510/65755BRA | ACTIVE | CDIP | J | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | JM38510/ 65755BRA | Samples |
| SN54HCT244J | ACTIVE | CDIP | J | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | SN54HCT244J | Samples |
| SN74HCT244DBR | ACTIVE | SSOP | DB | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HT244 | Samples |
| SN74HCT244DGSR | ACTIVE | VSSOP | DGS | 20 | 5000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | HT244 | Samples |
| SN74HCT244DW | ACTIVE | SOIC | DW | 20 | 25 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |
| SN74HCT244DWE4 | ACTIVE | SOIC | DW | 20 | 25 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |
| SN74HCT244DWG4 | ACTIVE | SOIC | DW | 20 | 25 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |
| SN74HCT244DWR | ACTIVE | SOIC | DW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |
| SN74HCT244DWRE4 | ACTIVE | SOIC | DW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |
| SN74HCT244DWRG4 | ACTIVE | SOIC | DW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |



| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|---------------------|--------------------------------------|----------------------|--------------|--------------------------------|---------|
| SN74HCT244N | ACTIVE | PDIP | N | 20 | 20 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 85 | SN74HCT244N | Samples |
| SN74HCT244NE4 | ACTIVE | PDIP | Ν | 20 | 20 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 85 | SN74HCT244N | Samples |
| SN74HCT244NSR | ACTIVE | SO | NS | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |
| SN74HCT244PW | ACTIVE | TSSOP | PW | 20 | 70 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HT244 | Samples |
| SN74HCT244PWE4 | ACTIVE | TSSOP | PW | 20 | 70 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HT244 | Samples |
| SN74HCT244PWG4 | ACTIVE | TSSOP | PW | 20 | 70 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HT244 | Samples |
| SN74HCT244PWR | ACTIVE | TSSOP | PW | 20 | 2000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 85 | HT244 | Samples |
| SN74HCT244PWRG4 | ACTIVE | TSSOP | PW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HT244 | Samples |
| SN74HCT244PWT | ACTIVE | TSSOP | PW | 20 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HT244 | Samples |
| SNJ54HCT244FK | ACTIVE | LCCC | FK | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 85130012A SNJ54HCT 244FK | Samples |
| SNJ54HCT244J | ACTIVE | CDIP | J | 20 | 1 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 8513001RA SNJ54HCT244J | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54HCT244, SN54HCT244-SP, SN74HCT244 :

- Catalog : SN74HCT244, SN54HCT244
- Automotive : SN74HCT244-Q1, SN74HCT244-Q1
- Enhanced Product : SN74HCT244-EP, SN74HCT244-EP
- Military : SN54HCT244
- Space : SN54HCT244-SP

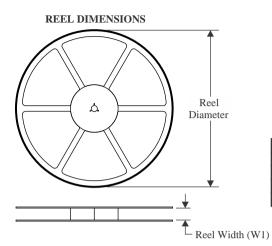
NOTE: Qualified Version Definitions:

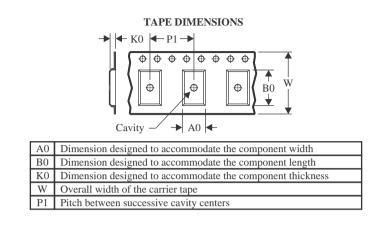
- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

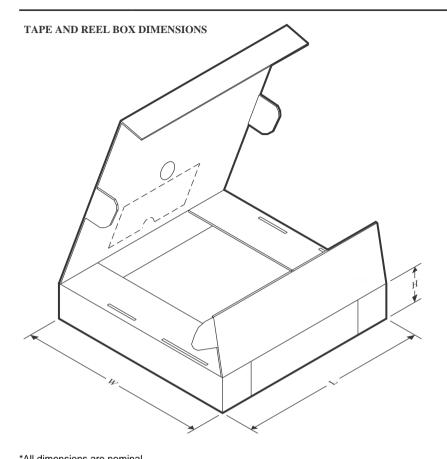


| *All dimensions are nominal | | | | | | | | | | | | |
|-----------------------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| SN74HCT244DBR | SSOP | DB | 20 | 2000 | 330.0 | 16.4 | 8.2 | 7.5 | 2.5 | 12.0 | 16.0 | Q1 |
| SN74HCT244DBR | SSOP | DB | 20 | 2000 | 330.0 | 16.4 | 8.2 | 7.5 | 2.5 | 12.0 | 16.0 | Q1 |
| SN74HCT244DGSR | VSSOP | DGS | 20 | 5000 | 330.0 | 16.4 | 5.4 | 5.4 | 1.45 | 8.0 | 16.0 | Q1 |
| SN74HCT244DWR | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.9 | 13.3 | 2.7 | 12.0 | 24.0 | Q1 |
| SN74HCT244NSR | SO | NS | 20 | 2000 | 330.0 | 24.4 | 8.4 | 13.0 | 2.5 | 12.0 | 24.0 | Q1 |
| SN74HCT244NSR | SO | NS | 20 | 2000 | 330.0 | 24.4 | 8.4 | 13.0 | 2.5 | 12.0 | 24.0 | Q1 |
| SN74HCT244PWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.1 | 1.6 | 8.0 | 16.0 | Q1 |
| SN74HCT244PWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| SN74HCT244PWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| SN74HCT244PWRG4 | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| SN74HCT244PWRG4 | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| SN74HCT244PWT | TSSOP | PW | 20 | 250 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |



PACKAGE MATERIALS INFORMATION

24-Dec-2022



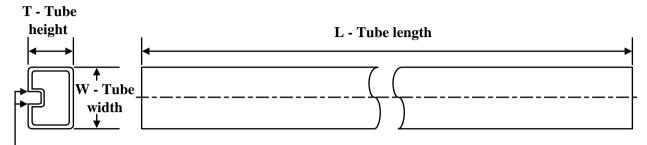
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74HCT244DBR | SSOP | DB | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244DBR | SSOP | DB | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244DGSR | VSSOP | DGS | 20 | 5000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244DWR | SOIC | DW | 20 | 2000 | 367.0 | 367.0 | 45.0 |
| SN74HCT244NSR | SO | NS | 20 | 2000 | 367.0 | 367.0 | 45.0 |
| SN74HCT244NSR | SO | NS | 20 | 2000 | 367.0 | 367.0 | 45.0 |
| SN74HCT244PWR | TSSOP | PW | 20 | 2000 | 364.0 | 364.0 | 27.0 |
| SN74HCT244PWR | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244PWR | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244PWRG4 | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244PWRG4 | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244PWT | TSSOP | PW | 20 | 250 | 356.0 | 356.0 | 35.0 |

TEXAS INSTRUMENTS

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TUBE



- B - Alignment groove width

| *All dimensions are nominal | |
|-----------------------------|--|
| | |

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | Τ (μm) | B (mm) |
|------------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| 5962-8513001VSA | W | CFP | 20 | 1 | 506.98 | 26.16 | 6220 | NA |
| 85130012A | FK | LCCC | 20 | 1 | 506.98 | 12.06 | 2030 | NA |
| JM38510/65755B2A | FK | LCCC | 20 | 1 | 506.98 | 12.06 | 2030 | NA |
| M38510/65755B2A | FK | LCCC | 20 | 1 | 506.98 | 12.06 | 2030 | NA |
| SN74HCT244DW | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| SN74HCT244DWE4 | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| SN74HCT244DWG4 | DW | SOIC | 20 | 25 | 507 | 12.83 | 5080 | 6.6 |
| SN74HCT244N | N | PDIP | 20 | 20 | 506 | 13.97 | 11230 | 4.32 |
| SN74HCT244NE4 | N | PDIP | 20 | 20 | 506 | 13.97 | 11230 | 4.32 |
| SN74HCT244PW | PW | TSSOP | 20 | 70 | 530 | 10.2 | 3600 | 3.5 |
| SN74HCT244PWE4 | PW | TSSOP | 20 | 70 | 530 | 10.2 | 3600 | 3.5 |
| SN74HCT244PWG4 | PW | TSSOP | 20 | 70 | 530 | 10.2 | 3600 | 3.5 |
| SNJ54HCT244FK | FK | LCCC | 20 | 1 | 506.98 | 12.06 | 2030 | NA |

LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N**) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



DB0020A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



DB0020A

EXAMPLE BOARD LAYOUT

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DB0020A

EXAMPLE STENCIL DESIGN

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



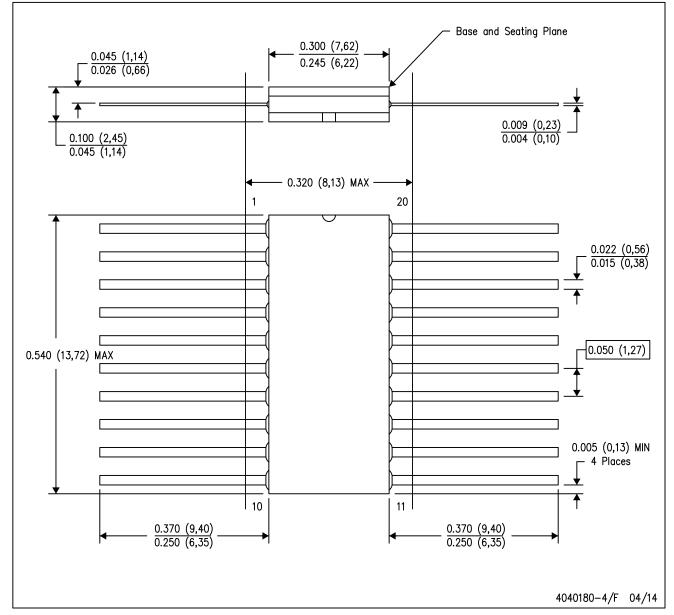
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice. В.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification only.
 E. Falls within Mil-Std 1835 GDFP2-F20



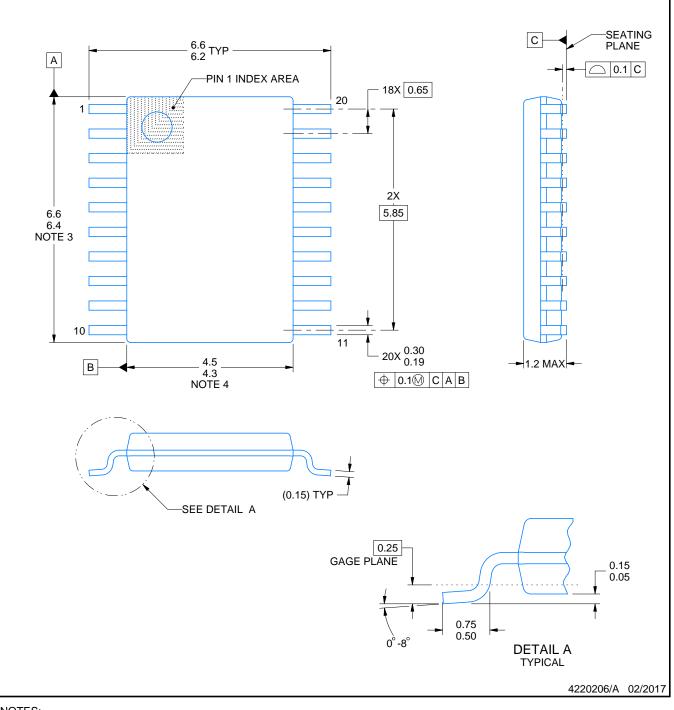
PW0020A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0020A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0020A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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